Complementary Silicon Plastic Power Transistors

- ... designed for use as high-frequency drivers in audio amplifiers.
- DC Current Gain Specified to 5.0 Amperes

hFE = 50 (Min) @ IC = 0.5 Adc

= 10 (Min) @ I_C = 2.0 Adc

- - VCEO(sus) = 250 Vdc (Min) MJE15032, MJE15033
- High Current Gain Bandwidth Product
 - $f_T = 30 \text{ MHz (Min)} @ I_C = 500 \text{ mAdc}$
- TO-220AB Compact Package

MAXIMUM RATINGS

Rating	Symbol	MJE15032 MJE1 <mark>5033</mark>	Unit
Collector–Emitter Voltage	VCEO	250	Vdc
Collector–Base Voltage	VCB	250	Vdc
Emitter–Base Voltage	VEB	5.0	Vdc
Collector Current — Continuous — Peak	lC	8.0 16	Adc
Base Current	ΙΒ	2.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	50 0.40	Watts W/°C
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	2.0 0.016	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

dzsc.com

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	°C/W

eferred devices are Motorola recommended choices for future use and best overall value.

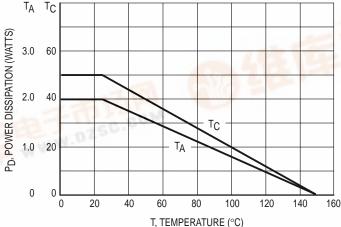


Figure 1. Power Derating

NPN MJE15032* PNP MJE15033*

*Motorola Preferred Device

8.0 AMPERES **POWER TRANSISTORS** COMPLEMENTARY SILICON 250 VOLTS **50 WATTS**



ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (1) $(I_C = 10 \text{ mAdc}, I_B = 0)$	MJE15032, MJE15033	VCEO(sus)	250	_	Vdc
Collector Cutoff Current (V _{CB} = 150 Vdc, I _E = 0)	MJE15032, MJE15033	ICBO	_	10	μAdc
Emitter Cutoff Current (VBE = 5.0 Vdc, I _C = 0)		IEBO		10	μAdc
ON CHARACTERISTICS (1)					
DC Current Gain ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 1.0 \text{ Adc}$, $V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 2.0 \text{ Adc}$, $V_{CE} = 5.0 \text{ Vdc}$)		hFE	50 50 10	_ _ _	_
Collector–Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc)		V _{CE(sat)}	_	0.5	Vdc
Base–Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)		V _{BE(on)}	_	1.0	Vdc
DYNAMIC CHARACTERISTICS					
Current Gain — Bandwidth Product (2) (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 1.0 MHz)		fΤ	30	_	MHz

⁽¹⁾ Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

⁽²⁾ $f_T = |h_{fe}| \cdot f_{test}$

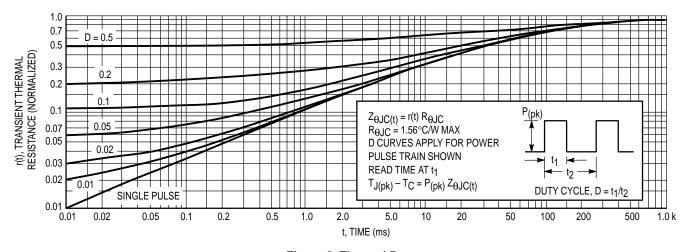


Figure 2. Thermal Response

M. 15: 15. T. 1: 5: 15.

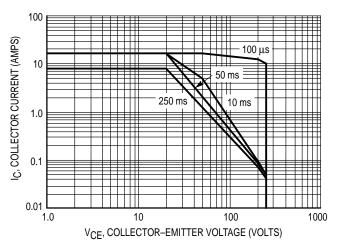


Figure 3. MJE15032 & MJE15033 Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{\text{C}} - V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation then the curves indicate.

The data of Figures 3 and 4 is based on $T_{J(pk)} = 150^{\circ} C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^{\circ} C$. $T_{J(pk)}$ may be calculated from the data in Figure 2. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

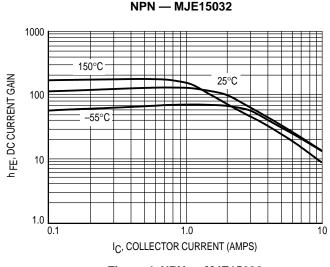


Figure 4. NPN — MJE15032 VCE = 5 V DC Current Gain

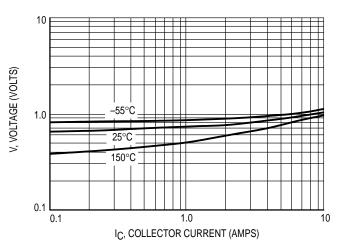


Figure 6. NPN — MJE15032 VCE = 5 V VBE(on) Curve

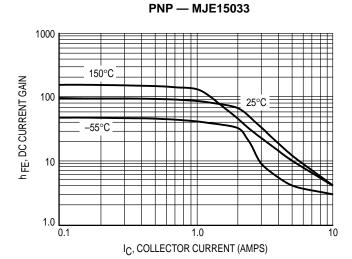


Figure 5. PNP — MJE15033 VCE = 5 V DC Current Gain

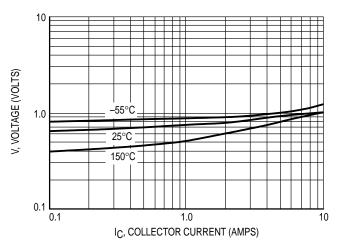


Figure 7. PNP — MJE15033 VCE = 5 V VBE(on) Curve



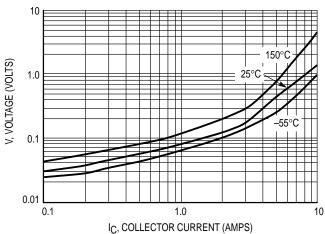
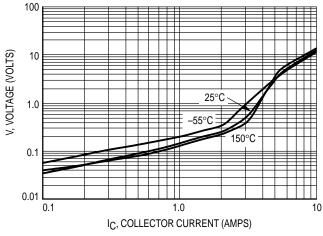


Figure 8. NPN — MJE15032 VCE(sat) IC/IB = 10



PNP — MJE15033

Figure 9. PNP — MJE15033 VCE(sat) IC/IB = 10

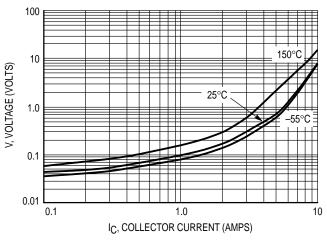


Figure 10. NPN — MJE15032 VCE(sat) IC/IB = 20

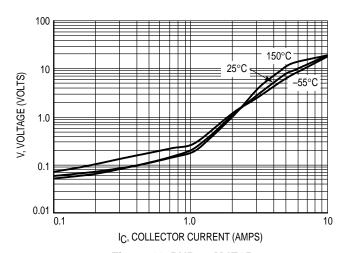


Figure 11. PNP — MJE15033 VCE(sat) IC/IB = 20

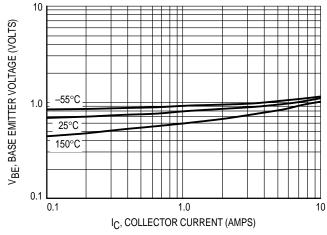


Figure 12. NPN — MJE15032 $V_{BE(sat)} I_C/I_B = 10$

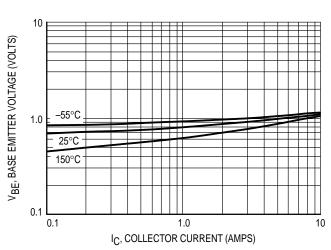
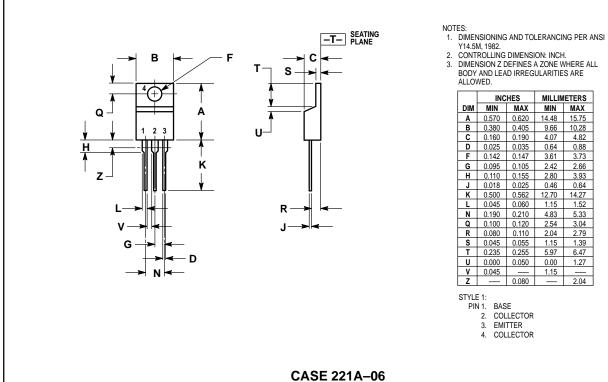


Figure 13. PNP — MJE15033 $V_{BE(sat)}I_{C}/I_{B} = 10$

PACKAGE DIMENSIONS

TO-220AB **ISSUE Y**



	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
7	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
ø	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
5	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

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